Features

- EE Programmable 65,536 x 1-, 131,072 x 1-, and 262,144 x 1-bit Serial Memories Designed to Store Configuration Programs for Field Programmable Gate Arrays (FPGAs)
- In-System Programmable via 2-wire Bus
- Simple Interface to SRAM FPGAs
- Compatible with Atmel AT6000, AT40K FPGAs, Altera FLEX[®] Devices, Lucent ORCA[®] FPGAs, Xilinx XC3000, XC4000, XC5200, SPARTAN[®] FPGAs, Motorola MPA1000 FPGAs
- Cascadable Read Back to Support Additional Configurations or Future Higher-density Arrays (128K and 256K only)
- Low-power CMOS EEPROM Process
- Programmable Reset Polarity
- Available in the Space-efficient Plastic DIP or SOIC Packages; PLCC Package is Pin-compatible Across Product Family
- Emulation of Atmel's AT24CXXX Serial EEPROMs
- Available in 3.3V \pm 10% LV and 5V \pm 5% C Versions
- Low-power Standby Mode

Description

The AT17C65/128/256 and AT17LV65/128/256 (low-density AT17 Series) FPGA Configuration EEPROMs (Configurators) provide an easy-to-use, cost-effective configuration memory for Field Programmable Gate Arrays. The low-density AT17 Series is packaged in the 8-pin PDIP, 8-lead SOIC, and the popular 20-lead PLCC and SOIC. The AT17 Series family uses a simple serial-access procedure to configure one or more FPGA devices. The AT17 Series organization supplies enough memory to configure one or multiple smaller FPGAs. Using a feature of the AT17 Series, the user can select the polarity of the reset function by programming a special EEPROM byte. These devices also support a write-protection mechanism within its programming mode.

The AT17 Series Configurators can be programmed with industry-standard programmers, or Atmel's ATDH2200E Programming Kit.

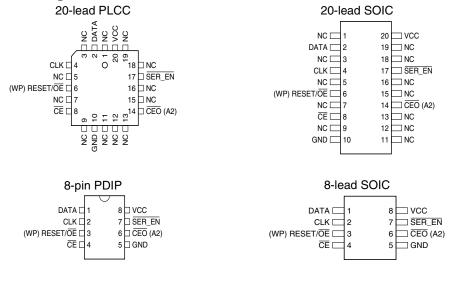
AMEL

FPGA Configuration EEPROM Memory

64K, 128K and 256K

AT17C65 AT17LV65 AT17C128 AT17LV128 AT17C256 AT17LV256

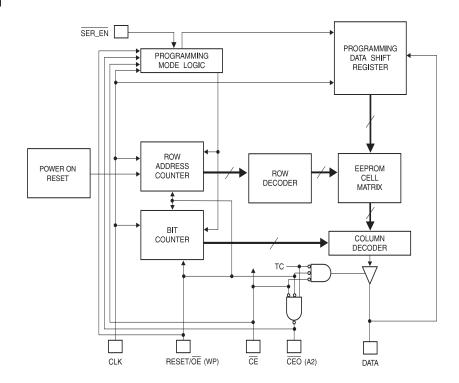
Pin Configurations







Block Diagram



FPGA Master Serial Mode Summary

The I/O and logic functions of the FPGA and their associated interconnections are established by a configuration program. The program is loaded either automatically upon power-up, or on command, depending on the state of the FPGA mode pins. In Master Mode, the FPGA automatically loads the configuration program from an external memory. The AT17 Serial Configuration EEPROM has been designed for compatibility with the Master Serial Mode.

This document discusses the AT6000 FPGA interface. For more details or AT40K FPGA applications, please reference "AT6000 Series Configuration" or "AT40K Series Configuration" application notes.

Controlling the Low-density AT17 Series Serial EEPROMs During Configuration

Most connections between the FPGA device and the AT17 Serial EEPROM are simple and self-explanatory.

- The DATA output of the AT17 Series Configurator drives DIN of the FPGA devices.
- The master FPGA CCLK output drives the CLK input of the AT17 Series Configurator.

- The CEO output of any AT17C/LV128/256 drives the CE input of the next AT17C/LV128/256 in a cascade chain of EEPROMs. An AT17C/LV65 can only be used at the end of a cascade chain or as a standalone device.
- SER_EN must be connected to VCC (except during ISP).

There are two different ways to use the inputs \overline{CE} and \overline{OE} .

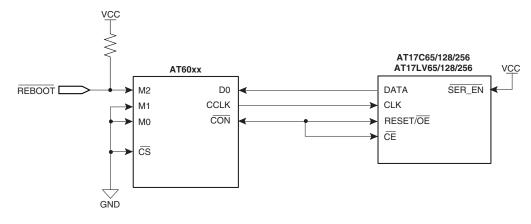
Condition 1

The simplest connection is to have the FPGA CON pin drive both CE and RESET/OE⁽¹⁾ in parallel (Figure 1). Due to its simplicity, however, this method will fail if the FPGA receives an external reset condition during the configuration cycle. If a system reset is applied to the FPGA, it will abort the original configuration and then reset itself for a new configuration, as intended. Of course, the AT17 Series Configurator does not see the external reset signal and will not reset its internal address counters and, consequently, will remain out of sync with the FPGA for the remainder of the configuration cycle.

Note: 1. For this condition, the reset polarity of the EEPROM must be set active High.

2

Figure 1. Condition 1 Connection



Notes: 1. 4.7 k Ω resistors used unless otherwise specified.

2. Reset polarity of EEPROM must be set active High.

Condition 2

The FPGA $\overline{\text{CON}}$ pin drives only the $\overline{\text{CE}}$ input of the AT17 Series Configurator, while the RESET/ $\overline{\text{OE}}$ input is driven by an input to the FPGA $\overline{\text{RESET}}$ input pin. This connection works under all normal circumstances, even when the user aborts a configuration before $\overline{\text{CON}}$ has gone High. A Low level on the RESET/ $\overline{\text{OE}}^{(1)}$ input – during FPGA reset – clears the Configurator's internal address pointer, so that the reconfiguration starts at the beginning.

Note: 1. For this condition, the reset polarity of the EEPROM must be set active Low.

The AT17 Series Configurator does not require an inverter for either condition since the RESET polarity is programmable.

Cascading Serial Configuration EEPROMs (AT17C/LV128 and AT17C/LV256 only)⁽¹⁾

For multiple FPGAs configured as a daisy-chain, or for future FPGAs requiring larger configuration memories, cascaded Configurators provide additional memory.

After the last bit from the first Configurator is read, the next clock signal to the Configurator asserts its \overline{CEO} output low and disables its DATA line driver. The second Configurator recognizes the Low level on its \overline{CE} input and enables its DATA output.

After configuration is complete, the address counters of all cascaded Configurators are reset if the RESET/ \overline{OE} on each Configurator is driven to its active (default High) level.

If the address counters are not to be reset upon completion, then the RESET/ $\overline{\text{OE}}$ input can be tied to its inactive (default Low) level.

Note: 1. A single AT17C/LV65 may be used at the end of a cascade chain.

AT17 Series Reset Polarity

The AT17 Series Configurator allows the user to program the reset polarity as either RESET/OE or RESET/OE. This feature is supported by industry-standard programmer algorithms. For more details on programming the EEPROM's reset polarity, please reference the "Programming Specification for Atmel's FPGA Configuration EEPROMs" application note.

Programming Mode

The programming mode is entered by bringing SER_EN Low. In this mode the chip can be programmed by the 2-wire serial bus. The programming is done at VCC supply only. Programming super voltages are generated inside the chip. See the "Programming Specification for Atmel's FPGA Configuration EEPROMs" application note for further information. The AT17C parts are read/write at 5V nominal. The AT17LV parts are read/write at 3.3V nominal.

Standby Mode

The AT17C/LV65/128/256 enters a low-power standby mode whenever \overline{CE} is asserted High. In this mode, the Configurator consumes less than 75 μ A of current at 5.0V. The output remains in a high impedance state regardless of the state of the \overline{OE} input.





Pin Configurations

20	8			
PLCC/	DIP/			
SOIC	SOIC			
Pin	Pin	Name	I/O	Description
2	1	DATA	I/O	Three-state DATA output for configuration. Open-collector bi-directional pin for programming.
4	2	CLK	I	Clock input. Used to increment the internal address and bit counter for reading and programming.
6	3	RESET/OE	I	RESET/Output Enable input (when $\overline{\text{SER}}_{EN}$ is High). A Low level on both the $\overline{\text{CE}}$ and RESET/ $\overline{\text{OE}}$ inputs enables the data output driver. A High level on RESET/ $\overline{\text{OE}}$ resets both the address and bit counters. The logic polarity of this input is programmable as either RESET/ $\overline{\text{OE}}$ or RESET/ $\overline{\text{OE}}$. This document describes the pin as RESET/ $\overline{\text{OE}}$.
		WP	I	Write protect (WP) input (when \overline{CE} is Low). When WP is Low, the entire memory can be written. When WP is enabled (High), the lowest block of the memory cannot be written. This feature is only active in the 2-wire serial Programming Mode (i.e., when \overline{SER}_{EN} is Low; see "Programming Specification" application note for more details).
8	4	CE	I	Chip Enable input. Used for device selection. A Low level on both \overline{CE} and \overline{OE} enables the data output driver. A High level on \overline{CE} disables both the address and bit counters and forces the device into a low-power standby mode. Note that this pin will <u>not</u> enable/disable the device in the 2-wire Serial Programming Mode (i.e., when <u>SER_EN</u> is Low).
10	5	GND		Ground pin. A 0.2 μ F decoupling capacitor between VCC and GND is recommended.
14	6	CEO	0	Chip Enable Output. This signal is asserted Low on the clock cycle following the last bit read from the memory. It will stay Low as long as \overline{CE} and \overline{OE} are both Low. It will then follow \overline{CE} until \overline{OE} goes High. Thereafter, \overline{CEO} will stay High until the entire EEPROM is read again.
		A2	I	Device selection input, A2. This is used to enable (or select) the device during programming (i.e. when SER_EN is Low; see the "Programming Specification" application note for more details.
17	7	SER_EN	I	Serial enable must be held High during FPGA loading operations. Bringing $\overline{\text{SER}_{EN}}$ Low enables the 2-wire Serial Programming Mode.
20	8	VCC		+3.3V/+5V Power Supply Pin.

Absolute Maximum Ratings*

Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground0.1V to V _{CC} +0.5V
Supply Voltage (V _{CC})0.5V to +7.0V
Maximum Soldering Temp. (10 sec. @ 1/16 in.)260°C
ESD (R _{ZAP} = 1.5K, C _{ZAP} = 100pF)

*NOTICE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those listed under operating conditions is not implied. Exposure to Absolute Maximum Rating conditions for extended periods of time may affect device reliability.

4

Operating Conditions

			AT17CXXX	AT17LVXXX	
Symbol	Description		Min/Max	Min/Max	Units
	Commercial	Supply voltage relative to GND -0°C to +70°C	4.75/5.25	3.0/3.6	V
V _{cc}	Industrial	Supply voltage relative to GND -40°C to +85°C	4.5/5.5	3.0/3.6	V
	Military	Supply voltage relative to GND -55°C to +125°C	4.5/5.5	5/5.25 3.0/3.6 5/5.5 3.0/3.6	V





DC Characteristics

 V_{CC} = 5V \pm 5% Commercial/5V \pm 10% Ind./Mil.

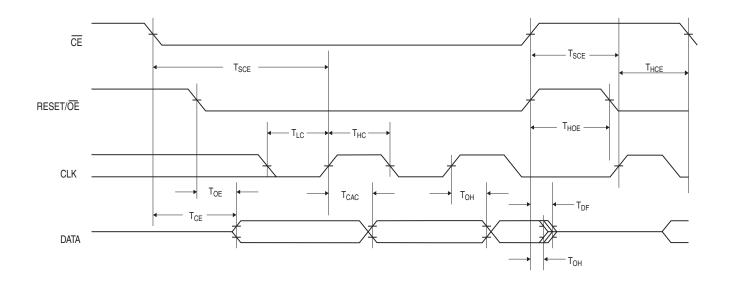
Symbol	Description		Min	Max	Units
V _{IH}	High-level input voltage		2.0	V _{cc}	V
V _{IL}	Low-level input voltage		0	0.8	V
V _{OH}	High-level output voltage (I _{OH} = -4 mA)	O a manufacture	3.7		V
V _{OL}	Low-level output voltage (I _{OL} = +4 mA)	Commercial		0.32	V
V _{OH}	High-level output voltage (I _{OH} = -4 mA)	la du stais l	3.6		V
V _{OL}	Low-level output voltage (I _{OL} = +4 mA)	Industrial		0.37	V
V _{OH}	High-level output voltage (I _{OH} = -4 mA)	N dilla - ma	3.5		V
V _{OL}	Low-level output voltage (I _{OL} = +4 mA)	Military		0.4	V
I _{CCA}	Supply current, active mode			10	mA
I _L	Input or output leakage current ($V_{IN} = V_{CC}$ or GND)		-10	10	μA
		Commercial		75	μA
I _{CCS}	Supply current, standby mode	Industrial/Military		150	μA

DC Characteristics

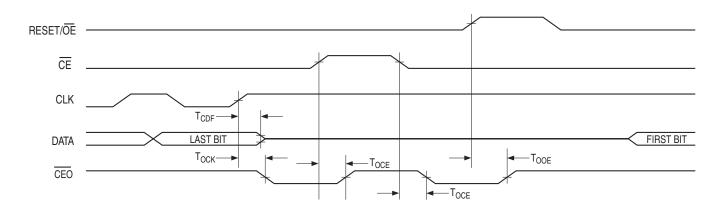
 $V_{\rm CC} = 3.3V \pm 10\%$

Symbol	Description		Min	Max	Units
V _{IH}	High-level input voltage		2.0	V _{CC}	V
V _{IL}	Low-level input voltage		0	0.8	V
V _{OH}	High-level output voltage (I _{OH} = -2.5 mA)	Commonsial	2.4		V
V _{OL}	Low-level output voltage (I _{OL} = +3 mA)	- Commercial		0.4	V
V _{OH}	High-level output voltage (I _{OH} = -2 mA)	Induction	2.4		V
V _{OL}	Low-level output voltage (I _{OL} = +3 mA)	Industrial		0.4	V
V _{OH}	High-level output voltage (I _{OH} = -2 mA)	N dilite ma	2.4		V
V _{OL}	Low-level output voltage ($I_{OL} = +2.5 \text{ mA}$)	– Military		0.4	V
I _{CCA}	Supply current, active mode			5	mA
IL	Input or output leakage current ($V_{IN} = V_{CC}$ or GND)		-10	10	μA
		Commercial		50	μA
I _{CCS}	Supply current, standby mode	Industrial/Military		100	μA

AC Characteristics



AC Characteristics When Cascading







AC Characteristics for AT17C65/128

 V_{CC} = 5V \pm 5% Commercial/V_{CC} = 5V \pm 10% Ind./Mil.

		Comn	nercial	Industrial	/Military ⁽¹⁾	
Symbol	Description	Min	Max	Min	Max	Units
T _{OE} ⁽²⁾	OE to Data Delay		30		35	ns
T _{CE} ⁽²⁾	CE to Data Delay		50		50	ns
T _{CAC} ⁽²⁾	CLK to Data Delay		50		55	ns
Т _{ОН}	Data Hold from \overline{CE} , \overline{OE} , or CLK	0		0		ns
$T_{DF}^{(3)}$	CE or OE to Data Float Delay		50		50	ns
T _{LC}	CLK Low Time	30		35		ns
Т _{НС}	CLK High Time	30		35		ns
T _{SCE}	CE Setup Time to CLK (to guarantee proper counting)	45		50		ns
T _{HCE}	CE Hold Time from CLK (to guarantee proper counting)	0		0		ns
T _{HOE}	OE High Time (guarantees counter is reset)	25		25		ns
F _{MAX}	MAX Input Clock Frequency	12.5		12.5		MHz

AC Characteristics for AT17C128 When Cascading

 V_{CC} = 5V± 5% Commercial/V $_{CC}$ = 5V ± 10% Ind./Mil.

		Comn	nercial	Industrial/Military ⁽¹⁾		
Symbol	Description	Min	Max	Min	Max	Units
T _{CDF} ⁽³⁾	CLK to Data Float Delay		50		50	ns
T _{OCK} ⁽²⁾	CLK to CEO Delay		55		60	ns
T _{OCE} ⁽²⁾	CE to CEO Delay		55		60	ns
T _{OOE} ⁽²⁾	RESET/OE to CEO Delay		40		45	ns
F _{MAX}	MAX Input Clock Frequency	8		8		MHz

Notes: 1. Preliminary specifications for military operating range only.

2. AC test load = 50 pF.

3. Float delays are measured with 5 pF AC loads. Transition is measured ±200 mV from steady state active levels.

AC Characteristics for AT17C256

 $V_{CC} = 5V \pm 5\%$ Commercial/ $V_{CC} = 5V \pm 10\%$ Ind./Mil.

		Comn	nercial	Industrial	/Military ⁽¹⁾	
Symbol	Description	Min	Max	Min	Max	Units
T _{OE} ⁽²⁾	OE to Data Delay		30		35	ns
T _{CE} ⁽²⁾	CE to Data Delay		45		45	ns
T _{CAC} ⁽²⁾	CLK to Data Delay		50		55	ns
Т _{ОН}	Data Hold from \overline{CE} , \overline{OE} , or CLK	0		0		ns
T _{DF} ⁽³⁾	CE or OE to Data Float Delay		50		50	ns
T _{LC}	CLK Low Time	20		20		ns
T _{HC}	CLK High Time	20		20		ns
T _{SCE}	CE Setup Time to CLK (to guarantee proper counting)	35		40		ns
T _{HCE}	CE Hold Time from CLK (to guarantee proper counting)	0		0		ns
T _{HOE}	OE High Time (guarantees counter is reset)	20		20		ns
F _{MAX}	MAX Input Clock Frequency	12.5		12.5		MHz

AC Characteristics for AT17C256 When Cascading

 V_{CC} = 5V±5% Commercial/V_{CC} = 5V ± 10% Ind./Mil.

		Comm	nercial	Industrial/Military ⁽¹⁾		
Symbol	Description	Min	Max	Min	Мах	Units
T _{CDF} ⁽³⁾	CLK to Data Float Delay		50		50	ns
T _{OCK} ⁽²⁾	CLK to CEO Delay		35		40	ns
T _{OCE} ⁽²⁾	CE to CEO Delay		35		35	ns
T _{OOE} ⁽²⁾	RESET/OE to CEO Delay		30		35	ns
F _{MAX}	MAX Input Clock Frequency	10		10		MHz

Notes: 1. Preliminary specifications for military operating range only.

2. AC test load = 50 pF.

3. Float delays are measured with 5 pF AC loads. Transition is measured ±200 mV from steady state active levels.





AC Characteristics for AT17LV65/128/256

 $V_{CC}=3.3V\pm10\%$

		Comr	nercial	Industrial	/Military ⁽¹⁾	
Symbol	Description	Min	Max	Min	Max	Units
T _{OE} ⁽²⁾	OE to Data Delay		50		55	ns
T _{CE} ⁽²⁾	CE to Data Delay		60		60	ns
T _{CAC} ⁽²⁾	CLK to Data Delay		75		80	ns
Т _{он}	Data Hold from \overline{CE} , \overline{OE} , or CLK	0		0		ns
T _{DF} ⁽³⁾	CE or OE to Data Float Delay		55		55	ns
T _{LC}	CLK Low Time	25		25		ns
T _{HC}	CLK High Time	25		25		ns
T _{SCE}	CE Setup Time to CLK (to guarantee proper counting)	35		60		ns
T _{HCE}	CE Hold Time from CLK (to guarantee proper counting)	0		0		ns
T _{HOE}	OE High Time (guarantees counter is reset)	25		25		ns
F _{MAX}	MAX Input Clock Frequency	10		10		MHz

AC Characteristics for AT17LV128/256 When Cascading

 $V_{CC} = 3.3V \pm 10\%$

		Comn	nercial	Industrial/Military ⁽¹⁾		
Symbol	Description	Min	Max	Min	Мах	Units
T _{CDF} ⁽³⁾	CLK to Data Float Delay		60		60	ns
T _{OCK} ⁽²⁾	CLK to CEO Delay		55		60	ns
T _{OCE} ⁽²⁾	CE to CEO Delay		55		60	ns
T _{OOE} ⁽²⁾	RESET/OE to CEO Delay		40		45	ns
F _{MAX}	MAX Input Clock Frequency	8		8		MHz

Notes: 1. Preliminary specifications for military operating range only.

2. AC test lead = 50 pF.

3. Float delays are measured with 5 pF AC loads. Transition is measured ±200 mV from steady state active levels.

Memory Size	Ordering Code	Package	Operation Range
64K	AT17C65-10PC	8P3	Commercial
	AT17C65-10NC	8S1	(0°C to 70°C)
	AT17C65-10JC	20J	
	AT17C65-10SC	20S	
	AT17C65-10PI	8P3	Industrial
	AT17C65-10NI	8S1	(-40°C to 85°C)
	AT17C65-10JI	20J	
	AT17C65-10SI	20S	
128K	AT17C128-10PC	8P3	Commercial
	AT17C128-10NC	8S1	(0°C to 70°C)
	AT17C128-10JC	20J	
	AT17C128-10SC	20S	
	AT17C128-10PI	8P3	Industrial
	AT17C128-10NI	8S1	(-40°C to 85°C)
	AT17C128-10JI	20J	
	AT17C128-10SI	20S	
256K	AT17C256-10PC	8P3	Commercial
	AT17C256-10NC	8S1	(0°C to 70°C)
	AT17C256-10JC	20J	
	AT17C256-10SC	20S	
	AT17C256-10PI	8P3	Industrial
	AT17C256-10NI	8S1	(-40°C to 85°C)
	AT17C256-10JI	20J	
	AT17C256-10SI	20S	

Package Type		
8P3	8-pin, 0.300" Wide, Plastic Dual Inline Package (PDIP)	
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)	
20J	20-lead, Plastic J-leaded Chip Carrier (PLCC)	
20S	20-lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)	





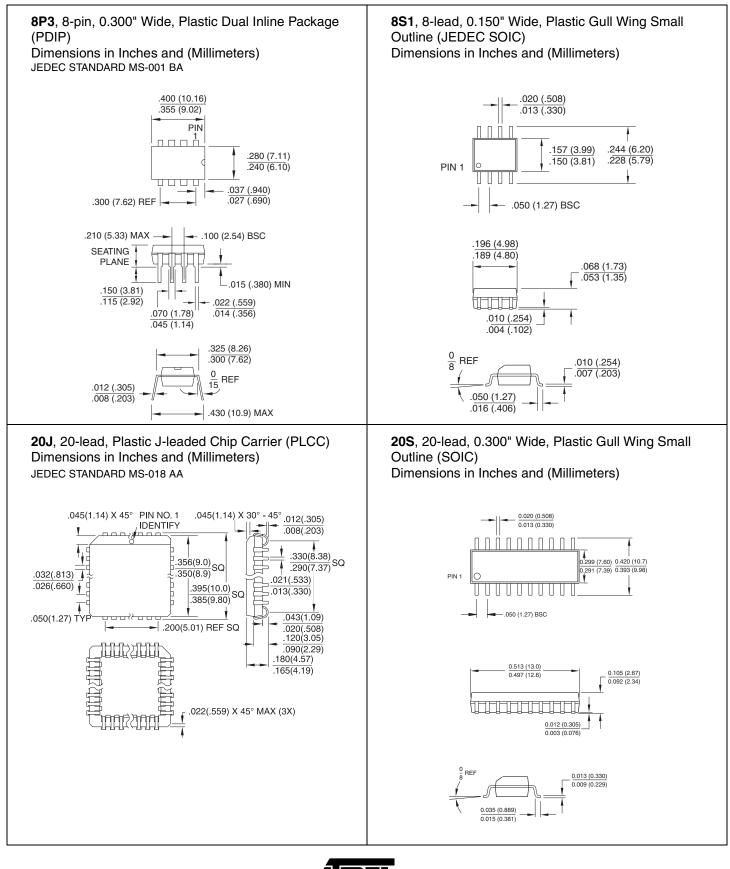
Ordering Information – 3.3V Devices

Memory Size	Ordering Code	Package	Operation Range
64K 	AT17LV65-10PC	8P3	Commercial
	AT17LV65-10NC	8S1	(0°C to 70°C)
	AT17LV65-10JC	20J	
	AT17LV65-10SC	20S	
	AT17LV65-10PI	8P3	Industrial
	AT17LV65-10NI	8S1	(-40°C to 85°C)
	AT17LV65-10JI	20J	
	AT17LV65-10SI	20S	
128K	AT17LV128-10PC	8P3	Commercial
	AT17LV128-10NC	8S1	(0°C to 70°C)
	AT17LV128-10JC	20J	
	AT17LV128-10SC	20S	
	AT17LV128-10PI	8P3	Industrial
	AT17LV128-10NI	8S1	(-40°C to 85°C)
	AT17LV128-10JI	20J	
	AT17LV128-10SI	20S	
256K	AT17LV256-10PC	8P3	Commercial
	AT17LV256-10NC	8S1	(0°C to 70°C)
	AT17LV256-10JC	20J	
	AT17LV256-10SC	20S	
	AT17LV256-10PI	8P3	Industrial
	AT17LV256-10NI	8S1	(-40°C to 85°C)
	AT17LV256-10JI	20J	
	AT17LV256-10SI	20S	

Package Type		
8P3	8-pin, 0.300" Wide, Plastic Dual Inline Package (PDIP)	
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)	
20J	20-lead, Plastic J-leaded Chip Carrier (PLCC)	
20S	20-lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)	

12 AT17C/LV65/12

Packaging Information





Atmel Headquarters

Corporate Headquarters 2325 Orchard Parkway San Jose, CA 95131 TEL (408) 441-0311 FAX (408) 487-2600

Europe

Atmel U.K., Ltd. Coliseum Business Centre Riverside Way Camberley, Surrey GU15 3YL England TEL (44) 1276-686-677 FAX (44) 1276-686-697

Asia

Atmel Asia, Ltd. Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimhatsui East Kowloon Hong Kong TEL (852) 2721-9778 FAX (852) 2722-1369

Japan

Atmel Japan K.K. 9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan TEL (81) 3-3523-3551 FAX (81) 3-3523-7581

Atmel Operations

Atmel Colorado Springs 1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 TEL (719) 576-3300 FAX (719) 540-1759

Atmel Rousset Zone Industrielle 13106 Rousset Cedex France TEL (33) 4-4253-6000 FAX (33) 4-4253-6001

Fax-on-Demand North America: 1-(800) 292-8635 International: 1-(408) 441-0732

e-mail literature@atmel.com

Web Site http://www.atmel.com

BBS 1-(408) 436-4309

© Atmel Corporation 2000.

Atmel Corporation makes no warranty for the use of its products, other than those expressly contained in the Company's standard warranty which is detailed in Atmel's Terms and Conditions located on the Company's web site. The Company assumes no responsibility for any errors which may appear in this document, reserves the right to change devices or specifications detailed herein at any time without notice, and does not make any commitment to update the information contained herein. No licenses to patents or other intellectual property of Atmel are granted by the Company in connection with the sale of Atmel products, expressly or by implication. Atmel's products are not authorized for use as critical components in life support devices or systems.

Marks bearing [®] and/or [™] are registered trademarks and trademarks of Atmel Corporation.

Terms and product names in this document may be trademarks of others.



Printed on recycled paper. 1636B-05/00/xM